

320A 30V N-channel Enhancement Mode Power MOSFET

Description

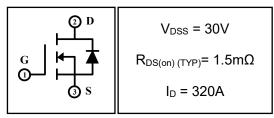
These N-channel enhancement mode power mosfets used advanced trench technology design, provided excellent Rdson and low gate charge. Which accords with the RoHS standard.

2 Features

- Low on resistance
- Low gate charge
- Fast switching
- Low reverse transfer capacitances
- 100% single pulse avalanche energy test
- 100% ΔV_{DS} test

3 Applications

- Power switching applications
- Inverter management system
- Electric tools
- Automotive electronics





4 Electrical Characteristics

4.1 Absolute Maximum Ratings (Tc=25 °C, unless otherwise noted)

| Parameter | | | Rating | | |
|-------------------------------------|---------------------------|------------------|--|---------------|------------|
| | | Symbol | DH012N03 DH012N03I/DH012N03E DH012N03B/DH012N03D | DH012N0 3F | Units |
| Drian-to-Source Voltage | | V _{DSS} | 30 | | V |
| Gate-to-Source Voltage | | V _{GSS} | ±20 | | V |
| Continuous Drain Current | T _C =25°C | | 320 | | Α |
| Continuous Drain Current | T _C =100℃ | - I _D | 226 | | Α |
| Pulsed Drain Current ⁽¹⁾ | | I _{DM} | 1280 | | Α |
| Single Pulse Avalanche Energ | y ⁽⁴⁾ | E _{AS} | 1600 | | mJ |
| Avalanche Current ⁽⁴⁾ | | I _{AS} | 80 | | Α |
| Dower Discipation | T _a =25℃ | P _{tot} | 2 | 2 | W |
| Power Dissipation | T _C =25℃ | P _{tot} | 270 80 | | W |
| Isolation Voltage | | V _{ISO} | 1 | 2500 | V |
| Junction Temperature Range | | Tj | - 55∼175 | | $^{\circ}$ |
| Storage Temperature Range | Storage Temperature Range | | - 55∼175 | | °C |

4.2 Thermal Characteristics

| 4.2 Thermal Gharacteristics | | | | | | |
|--|-------------------|--|---------------|-------|--|--|
| | | Rating | | | | |
| Parameter | Symbol | DH012N03 DH012N03I/DH012N03E DH012N03B/DH012N03D | DH012N0 3F | Units | | |
| Thermal Resistance,Junction to Case-sink | R _{thJC} | 0.55 | 1.88 | °C/W | | |
| Thermal Resistance, Junction to Ambient | R _{thJA} | 75 | 75 | °C/W | | |

DH012N03/DH012N03F/DH012N03I/ DH012N03E/DH012N03B/DH012N03D

4.3 Electrical Characteristics (Tc=25 °C ,unless otherwise noted)

| D | 0 | Test Condition | | Value | | Units |
|---|---------------------|---|-----|-------|------|-------|
| Parameter | Symbol | lest Condition | Min | Тур | Max | 1 |
| Off Characteristics | • | | | | | |
| Drain-to-Source Breakdown Voltage | BV _{DSS} | I _D =250μA,V _{GS} =0V | 30 | | | V |
| Drain-to-Source Leakage | 1 | V _{DS} =30V,V _{GS} =0V,T _C =25 °C | | | 1 | μA |
| Current | I _{DSS} | V _{DS} =30V,V _{GS} =0V,T _C =125 °C | | | 100 | μA |
| Gate-to-Source Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | | | ±100 | nA |
| On Characteristics | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS},I_{D}=250\mu A$ | 1 | 1.5 | 2 | V |
| Drain-to-Source on-state Resistance | R _{DS(on)} | V _{GS} =10V,I _D =160A | | 1.5 | 1.8 | mΩ |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C _{iss} | | | 8573 | | |
| Output Capacitance | Coss | V _{GS} =0V,V _{DS} =15V,f=1.0MHz | | 1266 | | pF |
| Reverse Transfer Capacitance | C _{rss} | VGS-0V, VDS-10V,1-1.0W112 | | 886 | | Pι |
| Gate Resisitance | R _G | V _{DD} =0V,V _{GS} =0V,F=1MHz | | 2.7 | | Ω |
| Switching Characteristics | | | | | | |
| Turn-on Delay Time | t _{d(on)} | I _D =160A, | | 32 | | |
| Turn-on Rise Time | t _r | V _{DD} =15V, | | 140 | | nS |
| Turn-off Delay Time | t _{d(off)} | V _{GS} =4.5V, | | 111 | | 113 |
| Turn-off Fall Time | t _f | R _{GEN} =2Ω | | 156 | | |
| Total Gate Charge | Qg | | | 209 | | |
| Gate-to-Source Charge | Q_{gs} | I _D =160A,V _{DD} =15V,V _{GS} =10V | | 31 | | nC |
| Gate-to-Drain("Miller") Charge | Q _{gd} | 15 1007 (, V 15 10 V , V (3 10 V | | 56.5 | | 110 |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage ⁽³⁾ | V _{SD} | V _{GS} =0V,I _S =160A | | | 1.3 | V |
| Diode Forward Current | Is | | | | 320 | Α |
| Reverse Recovery Time ⁽³⁾ | t _{rr} | TJ=25°C,I⊧=160A, | | 116 | | nS |
| Reverse Recovery Charge ⁽³⁾ | Q _{rr} | dl _F /dt=100A/μS,V _{GS} =0V | | 110 | | nC |

Notes:

- 1: Repetitive rating, pulse width limited by maximum junction temperature.
- 2: Surface mounted on FR4 Board, t≤10sec.
- 3: Pulse width \leq 300µs, duty cycle \leq 2%.
- 4: L=0.5mH,ID=80A,VDD=24V,VGATE=30V,Start TJ=25 $^{\circ}$ C .



5 Typical characteristics diagrams

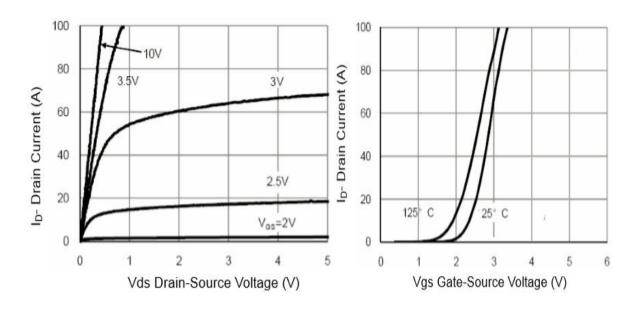


Figure 1 Output Characteristics

Figure 2 Transfer Characteristics

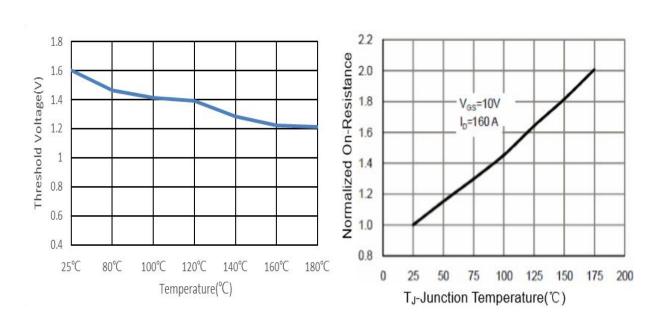
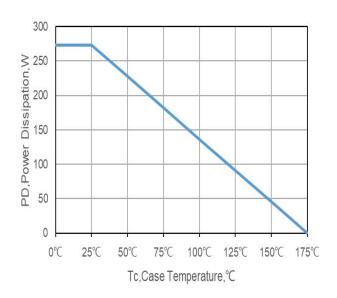


Figure 3. Threshold vs Temperature

Figure 4. Rdson vs Temperature



5 Typical characteristics diagrams(continues)



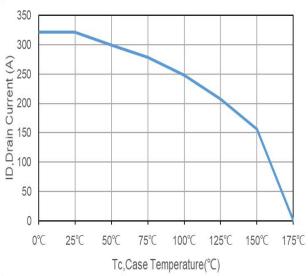


Figure 5. Power De-rating

Figure 6. ID Current Derating

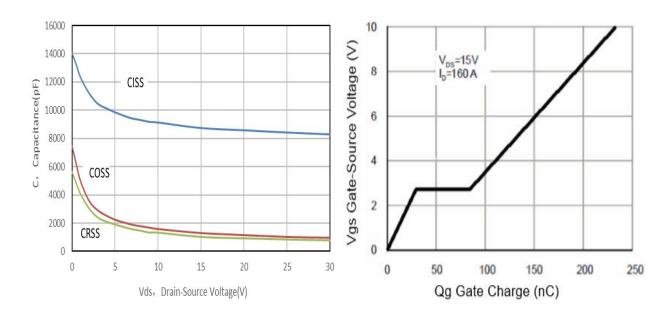


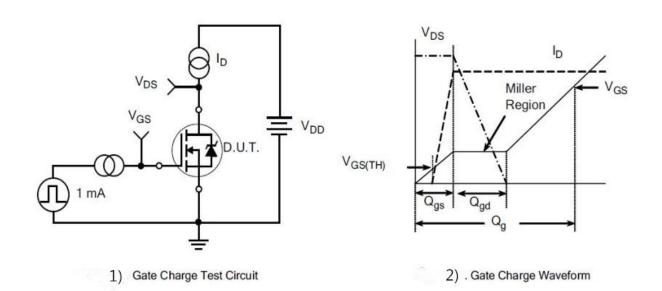
Figure 7. Capacitance Characteristics

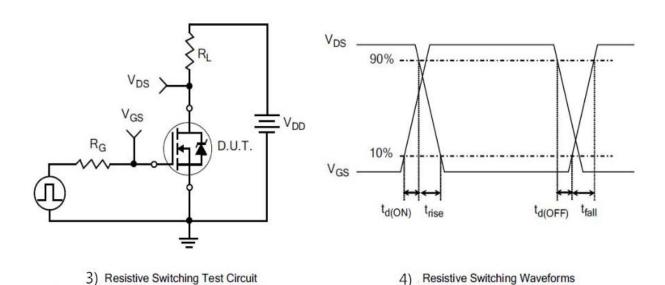
Figure 8. Gate Charge Characteristics

4) Resistive Switching Waveforms



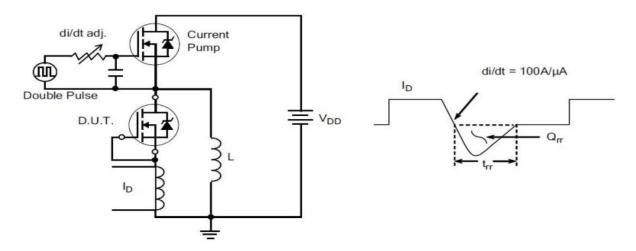
Typical Test Circuit and Waveform



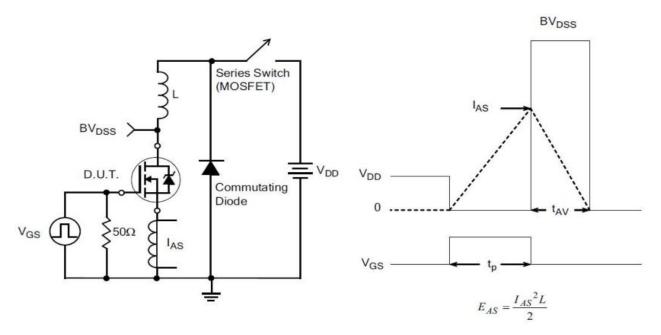




6 Typical Test Circuit and Waveform(continues)



- 5) Diode Reverse Recovery Test Circuit
- 6) Diode Reverse Recovery Waveform

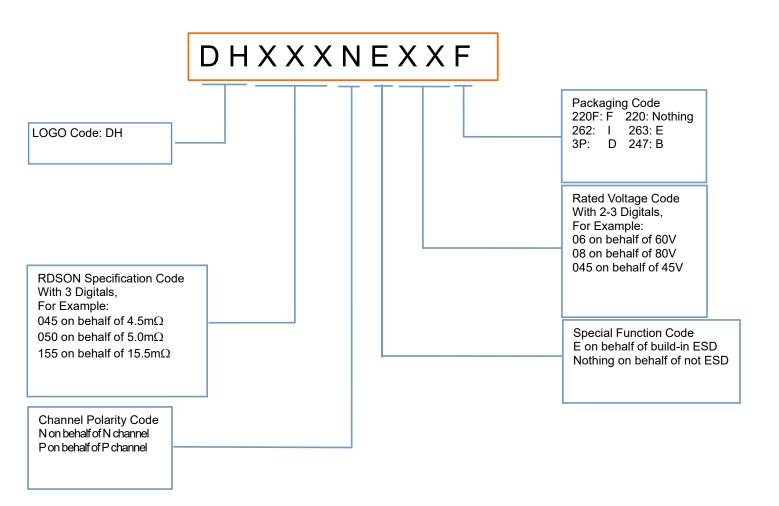


7) . Unclamped Inductive Switching Test Circuit

8) Unclamped Inductive Switching Waveforms



7 Product Names Rules



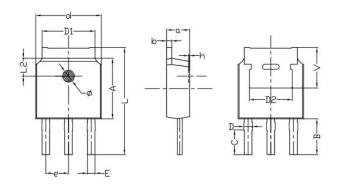
8 Product Specifications and Packaging Models

| Product Model | Package Type | Mark Name | RoHS | Package | Quantity |
|---------------|--------------|-----------|---------|-------------|----------|
| DH012N03 | TO-220 | DH012N03 | Pb-free | Tube | 1000/box |
| DH012N03F | TO-220F | DH012N03F | Pb-free | Tube | 1000/box |
| DH012N03B | TO-251 | DH012N03B | Pb-free | Tube | 3000/box |
| DH012N03D | TO-252 | DH012N03D | Pb-free | Tape & Reel | 2500/box |
| DH012N03I | TO-262 | DH012N03I | Pb-free | Tube | 1000/box |
| DH012N03E | TO-263 | DH012N03E | Pb-free | Tape & Reel | 800/box |



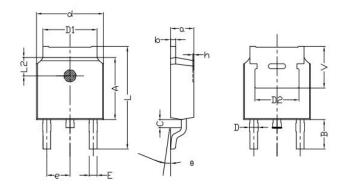
9 Dimensions

TO-251B PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions I | n Millimeters | Dimensions | In Inches | |
|--------|--------------|---------------|------------|-----------|--|
| Symbol | min. | max. | min. | max. | |
| a | 2. 20 | 2. 40 | 0. 087 | 0. 0946 | |
| b | 0.46 | 0. 58 | 0.018 | 0.023 | |
| C | 2. 45 | 2. 65 | 0.097 | 0. 104 | |
| D | 0.80 | 0. 90 | 0.032 | 0. 035 | |
| d | 6.30 | 6. 70 | 0. 248 | 0. 264 | |
| D1 | 5. 00 | 5. 50 | 0. 197 | 0.217 | |
| D2 | TYF | TYP 4.83 | | TYP 0.190 | |
| A | 5. 80 | 6. 20 | 0. 228 | 0. 244 | |
| e | 2. 19 | 2.39 | 0.086 | 0.094 | |
| L | 10. 40 | 11.00 | 0. 4098 | 0. 4334 | |
| В | 3. 50 | 3. 70 | 0. 1379 | 0. 1458 | |
| L2 | 1. 5 | 1.8 | 0.059 | 0.071 | |
| Ф | 1.10 | 1. 30 | 0. 0433 | 0.0512 | |
| h | 0.00 | 0. 30 | 0.000 | 0.012 | |
| V | 5. 25 | 5. 85 | 0. 207 | 0. 230 | |
| Е | 0.60 | 0.80 | 0. 0236 | 0. 0315 | |

TO-252B PACKAGE OUTLINE DIMENSIONS

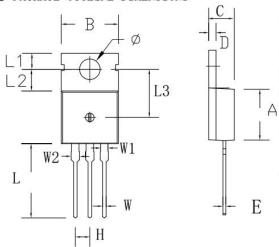


| C 1 1 | Dimensions In | n Millimeters | Dimensions | In Inches |
|--------|---------------|---------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| a | 2.20 | 2. 40 | 0.087 | 0.095 |
| b | 0.46 | 0.58 | 0.018 | 0.023 |
| c | 0.70 | 0. 90 | 0.028 | 0.035 |
| D | 0.80 | 1.00 | 0.032 | 0.039 |
| d | 6.30 | 6. 70 | 0. 248 | 0. 264 |
| D1 | 5.00 | 5. 50 | 0. 197 | 0.217 |
| D2 | TYP | TYP 4.83 | | . 190 |
| A | 5. 80 | 6. 20 | 0. 228 | 0. 244 |
| e | 2.19 | 2. 39 | 0.086 | 0.094 |
| L | 9. 40 | 10. 40 | 0.370 | 0.409 |
| В | 2.6 | 3. 2 | 0. 102 | 0. 126 |
| L2 | 1.5 | 1.8 | 0.059 | 0.071 |
| θ | 0 | 8 | 0 | 8 |
| h | 0 | 0.3 | 0 | 0.012 |
| V | 5. 25 | 5. 85 | 0. 207 | 0. 230 |
| Е | 0.6 | 0.8 | 0.024 | 0.032 |

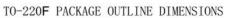


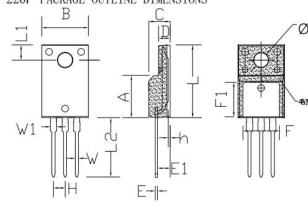
9 Dimensions(continues)

TO-220C PACKAGE OUTLINE DIMENSIONS



| Cl 1 | Dimensions Ir | Millimeters | Dimensions | In Inches |
|--------|---------------|-------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| A | 8.80 | 9.30 | 0.346 | 0.366 |
| В | 9.70 | 10.30 | 0. 382 | 0.406 |
| C | 4. 25 | 4.75 | 0. 167 | 0.187 |
| D | 1.20 | 1.45 | 0.047 | 0.057 |
| Е | 0.40 | 0.60 | 0.016 | 0.024 |
| Н | 2. 54 TYP | | 0.100 TYP | |
| W | 0.60 | 0.95 | 0.024 | 0.037 |
| W1 | 1.05 | 1. 45 | 0.041 | 0.057 |
| W2 | 1. 20 | 1.60 | 0.047 | 0.063 |
| L | 12.60 | 13. 40 | 0.496 | 0.528 |
| L1 | 2. 45 | 2. 95 | 0. 096 | 0.116 |
| L2 | 3. 45 | 3. 95 | 0. 136 | 0.156 |
| L3 | 8. 15 | 8.65 | 0. 321 | 0.341 |
| Φ | 3. 50 | 3. 90 | 0. 138 | 0.154 |
| | + | | | |



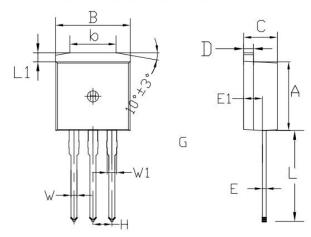


| CL.1 | Dimensions I | n Millimeters | Dimensions | In Inches |
|--------|--------------|---------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| A | 8. 80 | 9. 30 | 0.346 | 0.366 |
| В | 10.00 | 10.50 | 0.394 | 0.413 |
| С | 4. 30 | 4. 90 | 0. 169 | 0. 193 |
| D | 2. 30 | 2. 70 | 0.091 | 0.106 |
| L | 15. 55 | 16. 15 | 0.612 | 0.636 |
| h | 0.40 | 0.60 | 0.016 | 0.024 |
| L1 | 3. 15 | 3. 55 | 0. 124 | 0.140 |
| L2 | 12.65 | 13. 35 | 0.498 | 0. 526 |
| W | 0.70 | 0. 90 | 0.028 | 0.035 |
| W1 | 1.15 | 1. 55 | 0.045 | 0.061 |
| Н | 2.54 | TYP | 0. 100 TYP | |
| Е | 0.48 | 0. 53 | 0.019 | 0.021 |
| Φ | 2. 90 | 3. 40 | 0.114 | 0.134 |
| E1 | 2. 40 | 2. 90 | 0.094 | 0.114 |
| F | 7. 75 | 8. 25 | 0.305 | 0. 325 |
| F1 | 7. 35 | 7.85 | 0. 289 | 0.309 |

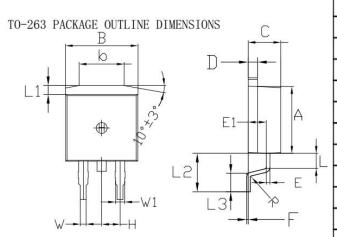


9 Dimensions(continues)

TO-262 PACKAGE OUTLINE DIMENSIONS



| CL . 1 | Dimensions In | Millimeters | Dimensions | In Inches |
|--------|---------------|-------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| A | 8. 80 | 9. 30 | 0.346 | 0.366 |
| В | 9. 70 | 10.30 | 0.382 | 0.406 |
| С | 4. 25 | 4. 75 | 0. 167 | 0. 187 |
| D | 1. 20 | 1. 45 | 0.047 | 0.057 |
| Е | 0.40 | 0.60 | 0.016 | 0.024 |
| L | 12, 25 | 13. 75 | 0. 482 | 0. 541 |
| L1 | 1. 15 | 1. 45 | 0.045 | 0.057 |
| E1 | 2. 4 | 2. 6 | 0.0945 | 0. 1024 |
| W | 0.80 | 0.82 | 0.0315 | 0.034 |
| W1 | 1. 20 | 1.30 | 0.047 | 0.051 |
| Н | 2. 5 | 4 TYP | 0. 200 | TYP |
| b | 5. 50 | 6. 50 | 0.216 | 0.256 |



| Camba 1 | Dimensions In | Millimeters | Dimensions | In Inches |
|---------|---------------|-------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| A | 8.80 | 9.30 | 0.346 | 0.366 |
| В | 9.70 | 10.30 | 0.382 | 0.406 |
| C | 4. 25 | 4. 75 | 0. 167 | 0.187 |
| D | 1.20 | 1. 45 | 0.047 | 0.057 |
| Е | 0.40 | 0.60 | 0.016 | 0.024 |
| L | 1.90 | 2. 30 | 0.075 | 0.091 |
| L1 | 1.15 | 1. 45 | 0.045 | 0.057 |
| R | 0.24 | 0. 26 | 0.0095 | 0.0102 |
| W | 0.80 | 0.82 | 0. 0315 | 0. 0323 |
| W1 | 1.20 | 1. 30 | 0.047 | 0.051 |
| Н | 2. 54 | 1 TYP | 0. 200 | TYP |
| b | 5. 50 | 6.50 | 0.216 | 0.256 |
| E1 | 2. 4 | 2.6 | 0.0946 | 0.1024 |
| L2 | 5. 20 | 5. 80 | 0. 205 | 0. 228 |
| L3 | 2. 20 | 3. 20 | 0.087 | 0.126 |
| F | 0. 03 | 0. 23 | 0.0012 | 0.0091 |

DH012N03/DH012N03F/DH012N03I/ DH012N03E/DH012N03B/DH012N03D

10 Attentions

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- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

| Date | REV. | Description | Page |
|------------|------|-------------|------|
| 2020.04.15 | 1.0 | Original | |